

**EAST Search History****EAST Search History (Prior Art)**

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	535769	@pd>"20090101"	US-PGPUB; USPAT; USOCR	OR	ON	2010/01/19 10:01
L2	27	(method and semiconductor and device and form and first and second and gate and electrode and (insulat\$3 or dielectric) and (layer or film) and source and drain and organic and material and etch).clm.	US-PGPUB; USPAT; USOCR	OR	ON	2010/01/19 10:01
L3	5	1 and L2	US-PGPUB; USPAT; USOCR	OR	ON	2010/01/19 10:01

1/19/2010 10:01:50 AM

C:\Documents and Settings\aho1\My Documents\EAST\Workspaces\10573328.wsp